NSN 5961-01-368-9012

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-368-9012 **Inclosure Material:** Plastic **Overall Length:** Between 0.175 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.675 inches **Overall Width:** Between 0.135 inches and 0.145 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.5 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes reverse breakdown current, dc and 10.00 milliamperes forward current, dc **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: